HD30648
SOLID STATE HIGH POWER AMPLIFIER

HD Communications Corp.



FEATURES

Rack mounted system
Class AB linear LDMOS design
Instantaneous UHF bandwidth
Suitable for all single channel modulation standards
Built-in protection circuits
High reliability and ruggedness

ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	400 - 500 MHz	
Power Output	1000 Watt Min	CW
Power Gain	60 dB Min	
Power Gain Flatness	2.0 dB p-p Max	
Input Return Loss	-10 dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	<-30 dBc Typ	50dBm/Tone, Δ = 1MHz
Harmonics	<-20 dBc Typ	
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	180 - 240 VAC	
Power Consumption	4000 Watt Max	At rated Pout
Input Power Protection	+8 dBm Max	<10 Sec without damage
Load VSWR Protection	∞: 1	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

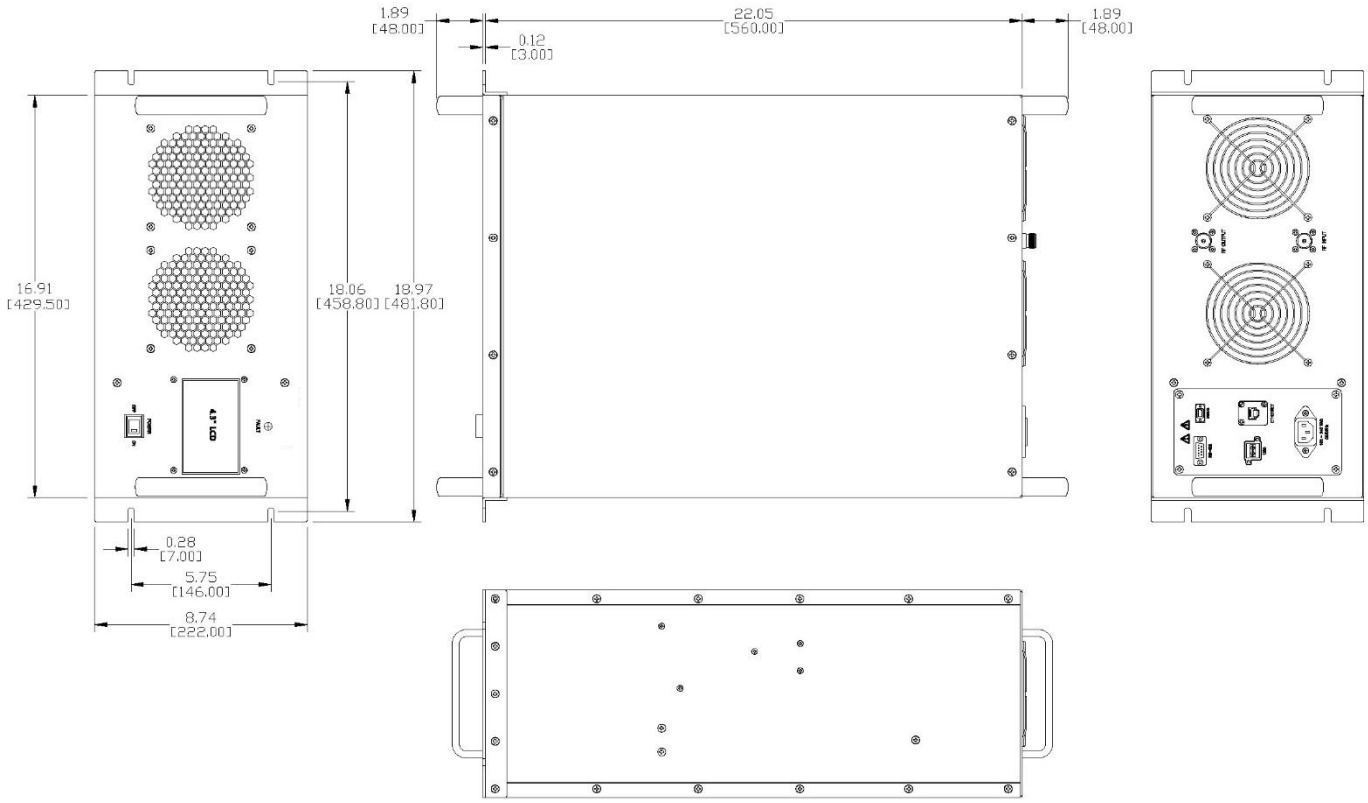
MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 222 x 560 mm	5U – Excluding connectors
Weight	35 Kg.	
RF Connectors In/Out	Type-N Female	Front or rear panel
AC Power / Interface	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, USB Optional GPIB Interface	Remote Bluetooth application

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OUTLINE DRAWING



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